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Pages 1 to 22

TRANSISTORS, NPN POWER TRANSISTOR

BASED ON TYPE 2N5926

ESA/SCC Detail Specification No. 5208/005



**space components
coordination group**

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DOCUMENTATION CHANGE NOTICE

Rev. Letter	Rev. Date	Reference	CHANGE Item	Approved DCR No.		
'A'	Feb. '92	This Issue incorporates all modifications agreed on the basis of Policy DCR 21016 for adaptation to new qualification requirements.				
		P1.	Cover page	None		
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		P4.	Table of Contents	: "Appendices" title added	21019	
		P5.	Para. 1.2	: Paragraph amended	21021	
		P6.	Table 1(a)	: "Lead Material and/or Finish" column amended	21025	
		P11.	Para. 2	: MIL-STD-1276 deleted, "ESA/SCC Basic Spec. No. 23500" added	21025	
			Para. 4.1	: Additional text added	21019	
			Para. 4.2.2	: PIND deviation deleted	21043	
		P13.	Para. 4.4.2	: Paragraph amended	21025	
		P18.	Table 3(a), (b)	: Reference to Note 2 deleted, Note 1 put under this table	21047	
				This document has been transferred from hardcopy to electronic format. The content is unchanged but minor differences in presentation exist.		
		'B'	Aug. '96	P1.	Cover page	None
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P5.	Para. 1.7			: Text amended	21083	



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APPENDICES (Applicable to specific Manufacturers only)

None.

**1. GENERAL****1.1 SCOPE**

This specification details the ratings, physical and electrical characteristics, test and inspection data for a Transistor, Power, NPN, based on Type 2N5926.

It shall be read in conjunction with ESA/SCC Generic Specification No. 5000, the requirements of which are supplemented herein.

1.2 COMPONENT TYPE VARIANTS

See Table 1(a).

1.3 MAXIMUM RATINGS

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the transistors specified herein are scheduled in Table 1(b).

1.4 PARAMETER DERATING INFORMATION

The derating information applicable to the transistors specified herein is shown in Figure 1.

1.5 PHYSICAL DIMENSIONS

The physical dimensions of the transistors specified herein are shown in Figure 2.

1.6 FUNCTIONAL DIAGRAM

The functional diagram showing lead identification, of the transistors specified herein, is shown in Figure 3.

1.7 HIGH TEMPERATURE TEST PRECAUTIONS

For tin-lead plated or solder-dipped lead finish, all tests to be performed at a temperature that exceeds +125°C shall be carried out in a 100% inert atmosphere.

TABLE 1(a) - TYPE VARIANTS

VARIANT	CASE	FIGURE	LEAD MATERIAL AND FINISH
01	TO63	2	D2
02	TO63	2	D3 or D4

**TABLE 1(b) - MAXIMUM RATINGS**

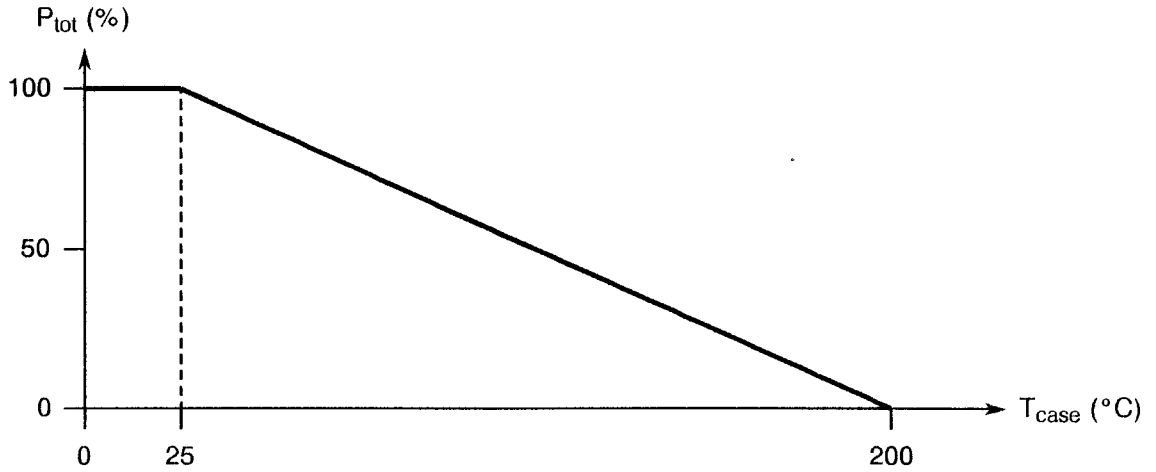
No.	CHARACTERISTICS	SYMBOL	MAXIMUM RATINGS	UNIT	REMARKS
1	Collector-Emitter Voltage	V_{CE}	120	Vdc	
2	Collector-Base Voltage	V_{CB}	150	Vdc	
3	Emitter-Base Voltage	V_{EB}	10	Vdc	
4	Emitter Current (Continuous)	I_E	50	Adc	
5	Base Current (Continuous)	I_B	10	Adc	
6	Power Dissipation (Continuous)	P_{tot}	350	W	$T_{case} \leq +25^{\circ}C$ Note 1
7	Operating Junction Temperature Range	T_{op}	- 65 to +200	$^{\circ}C$	
8	Storage Temperature Range	T_{stg}	- 65 to +200	$^{\circ}C$	
9	Soldering Temperature	T_{sol}	+260	$^{\circ}C$	Note 2

NOTES

1. For $T_{case} > +25^{\circ}C$, derate at $2.15^{\circ}C/W$.
2. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.



FIGURE 1(a) - PARAMETER DERATING INFORMATION



Power Dissipation versus Temperature

FIGURE 1(b) - SAFE OPERATING AREA (CONTINUOUS D.C.)

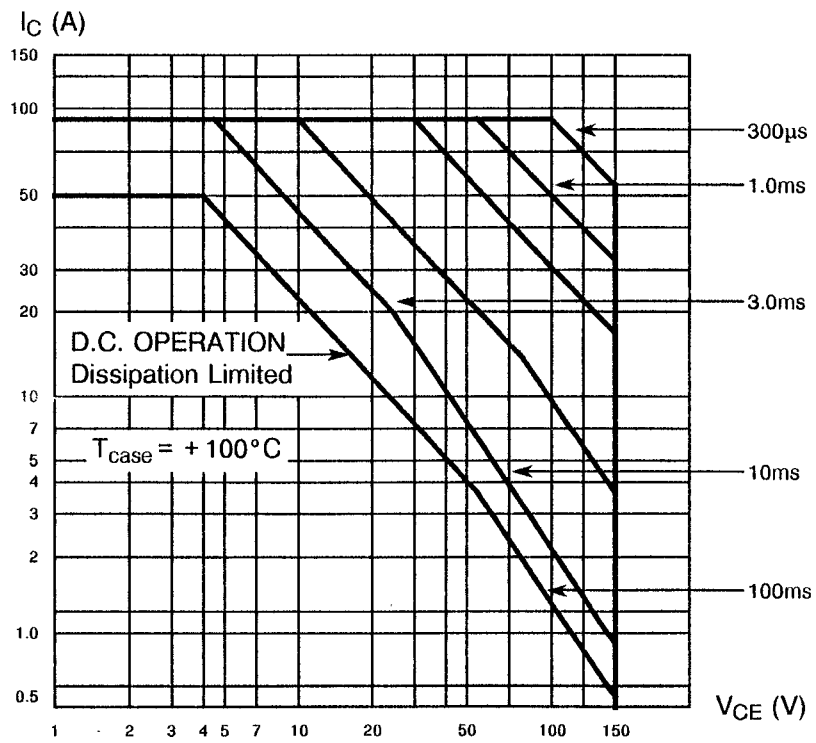
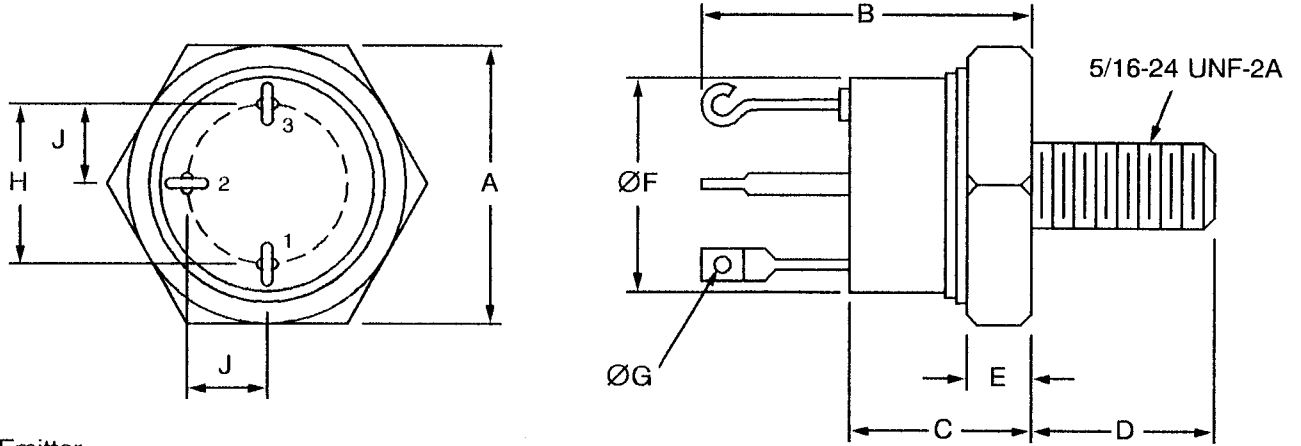




FIGURE 2 - PHYSICAL DIMENSIONS



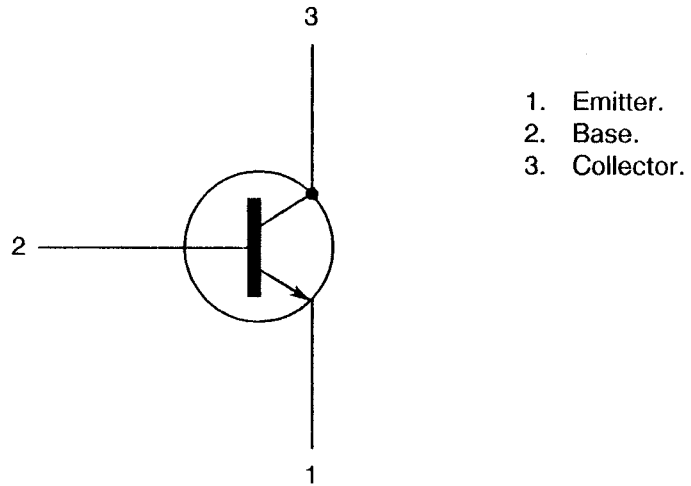
- 1. Emitter.
- 2. Base.
- 3. Collector.



SYMBOL	MILLIMETRES		NOTES
	MIN.	MAX.	
A	21.72	22.23	
B	24.76	26.16	
C	12.70	13.59	
D	11.68	12.57	
E	3.17	3.43	
ØF	19.05	19.43	
ØG	1.52	2.66	
H	12.40	12.90	
J	6.22	6.49	

NOTES

- 1. Index area: the leads shall be orientated as shown when viewed from above.
- 2. The collector shall be electrically connected to the case.

FIGURE 3 - FUNCTIONAL DIAGRAM AND SCHEMATIC SYMBOL



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2. APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 5000 for Discrete Semiconductor Components.
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices.
- (c) ESA/SCC Basic Specification No. 23500, Requirements for Lead Materials and Finishes for Components for Space Application.
- (d) MIL-STD-105, Sampling Procedure and Tables for Inspection by Attributes.

3. TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply.

4. REQUIREMENTS

4.1 GENERAL

The complete requirements for procurement of the transistors specified herein are stated in this specification and ESA/SCC Generic Specification No. 5000. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

4.2 DEVIATIONS FROM GENERIC SPECIFICATION

4.2.1 Deviations from Special In-process Controls

None.

4.2.2 Deviations from Final Production Tests (Chart II)

- (a) Para. 9.1, "Internal (Pre-encapsulation) Visual Inspection": Shall be performed in accordance with the Power Tech. Precap Visual document, dated 1st February 1974.
- (b) Para. 9.2.1, "Bond Strength Test": Shall not be performed.
- (c) Para. 9.6, "Constant Acceleration": Change Acceleration Level to 5000g.



4.2.3 Deviations from Burn-in and Electrical Measurements (Chart III)

(a) Para. 7.1.1(a), High Temperature Reverse Bias test: Not applicable.

4.2.4 Deviations from Qualification Tests (Chart IV)

None.

4.2.5 Deviations from Lot Acceptance Tests (Chart V)

None.

4.3 MECHANICAL REQUIREMENTS

4.3.1 Dimension Check

The dimensions of the transistors specified herein shall be checked. They shall conform to those shown in Figure 2.

4.3.2 Weight

The maximum weight of the transistors specified herein shall be 28.5 grammes.



4.3.3 Terminal Strength

The requirements for terminal strength testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. The test conditions shall be as follows:-

Terminal:

Test Condition: 'A' (Tension).
Applied Force: 10 lb.
Duration: 15 seconds.

Stud:

Test Condition: 'D2' (Stud Torque).
Applied Torque: 20 lb-in.
Duration: 15 seconds.

4.4 MATERIALS AND FINISHES

The materials and finishes shall be as specified herein. Where a definite material is not specified, a material which will enable the transistors specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

4.4.1 Case

The case shall be hermetically sealed and have a metal body with hard glass seals.

4.4.2 Lead Material and Finish

The lead material shall be Type 'D' with either Type '2' or Type '3 or 4' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

4.5 MARKING

4.5.1 General

The marking of all components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700. Each component shall be marked in respect of:-

- (a) The SCC Component Number.
- (b) Traceability Information.

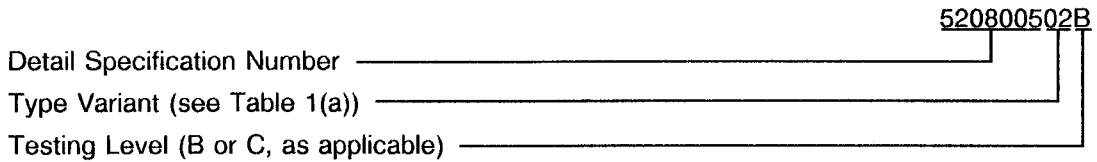
4.5.2 Lead Identification

Leads shall be positioned as shown in Figure 2. No lead identification shall be marked on the part.



4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:-



4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.

4.5.5 Marking of Small Components

When it is considered that the component is too small to accommodate the marking as specified above, as much as space permits shall be marked. The order of precedence shall be as follows:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

The marking information in full shall accompany each component in its primary package.

4.6 ELECTRICAL MEASUREMENTS

4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured at room temperature are scheduled in Table 2. Unless otherwise specified, measurements shall be performed at $T_{amb} = +25 \pm 3$ °C.

4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. The measurements shall be performed at $T_{amb} = -55(+5 - 0)$ and $+150(+0 - 5)$ °C respectively.



4.6.3 Circuits for Electrical Measurements

Circuits for use in performing the electrical measurements listed in Tables 2 and 3 are shown, where applicable, in MIL-STD-750 and in Figure 4 of this specification.

4.7 BURN-IN TESTS

4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, measurements shall be performed at $T_{amb} = +25 \pm 3$ °C. The parameter drift values (Δ) applicable to the parameters scheduled shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.

4.7.2 Conditions for Burn-in

The requirements for burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 5000. The conditions for burn-in shall be as specified in Table 5 of this specification.

4.7.3 Electrical Circuits for Burn-in

Not applicable.

**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS**

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN	MAX	
1	Collector-Base Breakdown Voltage	BV_{CBO}	3001 Bias Cond. D	$I_C = 200\mu A$ $I_E = 0A$	150	-	V
2	Collector-Emitter Breakdown Voltage	BV_{CEO}	3011 Bias Cond. D	$I_C = 200mA$ $I_B = 0A$ Note 1	120	-	V
2	Emitter-Base Breakdown Voltage	BV_{EBO}	3026 Bias Cond. D	$I_E = 1.0mA$ $I_C = 0A$	10	-	V
4	Collector-Emitter Cut-off Current	I_{CES}	3041 Bias Cond. C	$V_{BE} = 0V$ $V_{CE} = 120V$	-	1.0	mA
5	Emitter Cut-off Current	I_{EBO}	3061 Bias Cond. D	$V_{EB} = 8.0V$ $I_C = 0A$	-	1.0	mA
6	D.C. Forward Current Transfer Ratio 1	h_{FE1}	3076	$V_{CE} = 2.0V$ $I_C = 50A$ Note 1	10	40	-
7	D.C. Forward Current Transfer Ratio 2	h_{FE2}	3076	$V_{CE} = 2.0V$ $I_C = 30A$ Note 1	20	-	-
8	Collector Saturation Voltage	$V_{CE(SAT)}$	3071	$I_C = 50A$ $I_B = 5.0A$ Note 1	-	0.6	V
9	Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	3066	$I_C = 50A$ $V_{CE} = 5.0V$ Note 1	-	1.4	V

NOTES

- Pulsed measurement: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2.0\%$.
- If more than 20 units have to be measured, the measurements shall be made on a sample basis in accordance with Para. 7.4.2 of ESA/SCC Generic Specification No. 5000. Inspection Level II with an AQL = 1.0%.

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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST FIG.	TEST CONDITIONS (NOTE 2)	LIMITS		UNIT
						MIN	MAX	
10	A.C. Small Signal Current Gain	h_{fe}	3206	-	$V_{CE} = 10V$ $I_C = 1.0A$ $f = 100kHz$	8.0	-	-
11	Turn-on Time	t_{on}	-	4	$I_C = 15A$ $I_{B1} = I_{B2} = 1.5A$	-	6.0	μs
	Turn-off Time	t_{off}				-	10	

NOTES: See Page 16.

**TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES**

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN	MAX	
4	Collector-Emitter Cut-off Current	I_{CES}	3041 Bias Cond. C	$T_{amb} = +150^{\circ}C$ $V_{CE} = 120V$ $V_{BE} = 0V$ Note 1	-	10	mA
6	D.C. Forward Current Transfer Ratio 1	h_{FE1}	3076	$T_{amb} = -55^{\circ}C$ $I_C = 50A$ $V_{CE} = 2.0V$ Note 1	5.0	-	-

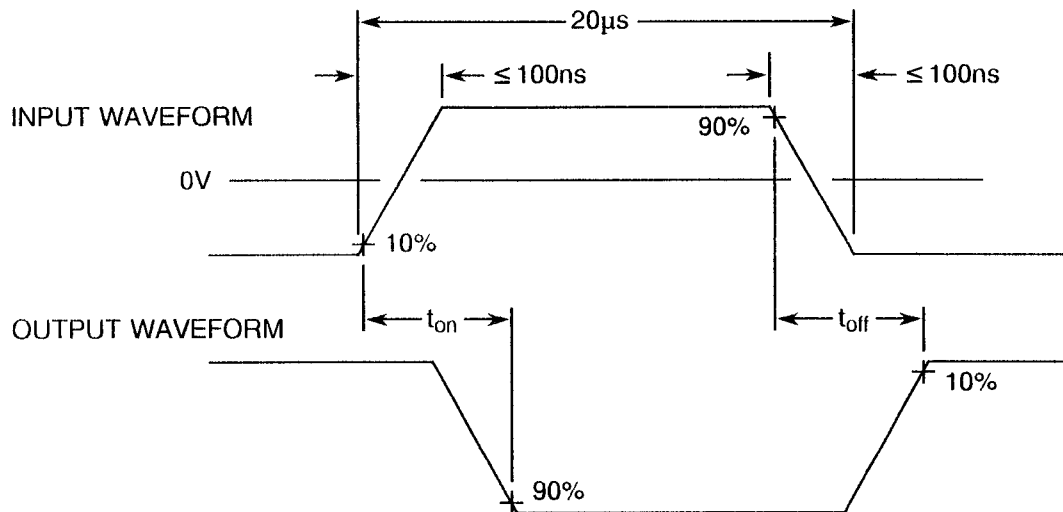
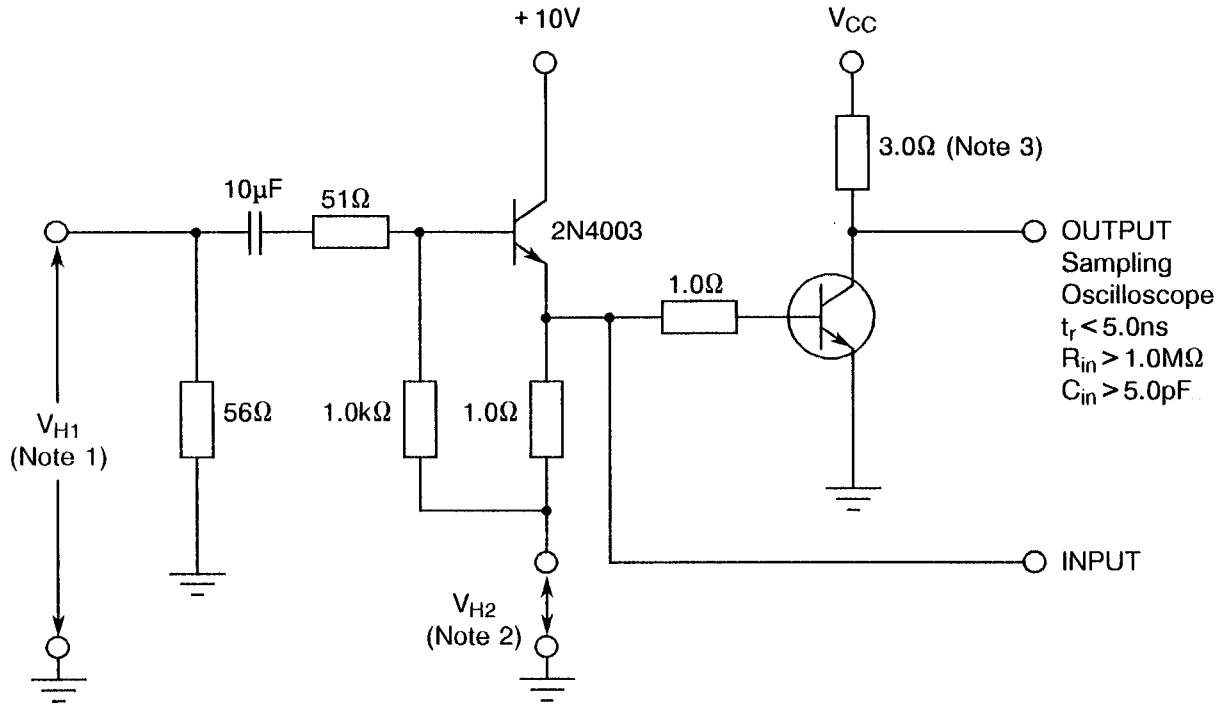
NOTES

1. Pulsed measurement: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2.0\%$.



FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS

TURN-ON AND TURN-OFF TIME



NOTES

1. Adjust V_{H1} for I_{B1} .
2. Adjust V_{H2} for I_{B2} .
3. All resistors are non-inductive.
4. Pulse rate $\leq 1.0\text{Hz}$.

**TABLE 4 - PARAMETER DRIFT VALUES**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)	UNIT
4	Collector-Emitter Cut-off Current	I_{CES}	As per Table 2	As per Table 2	± 200 or (1) $+ 100 - 50$	μA %
6	D.C. Forward Current Transfer Ratio 1	h_{FE1}	As per Table 2	As per Table 2	± 20	%
8	Collector Saturation Voltage	$V_{CE(SAT)}$	As per Table 2	As per Table 2	± 100	mV

NOTES

1. Whichever is greater, referred to the initial value.

TABLE 5 - CONDITIONS FOR POWER BURN-IN AND OPERATING LIFE TESTS

No.	CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT
1	Ambient Temperature	T_{amb}	$+ 100(+ 0 - 5)$	$^{\circ}C$
2	Collector-Base Voltage	V_{CB}	40	V
3	Power Dissipation	P_{tot}	200	W
4	Test Method 1039 of MIL-STD-750	-	B	-



- 4.8 ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC SPECIFICATION NO. 5000)
- 4.8.1 Electrical Measurements on Completion of Environmental Tests
The parameters to be measured on completion of environmental tests are scheduled in Table 2. The measurements shall be performed at $T_{amb} = +25 \pm 3$ °C.
- 4.8.2 Electrical Measurements at Intermediate Points during Endurance Tests
The parameters to be measured at intermediate points during endurance tests are scheduled in Table 6 of this specification.
- 4.8.3 Electrical Measurements on Completion of Endurance Tests
The parameters to be measured on completion of endurance testing are scheduled in Table 6 of this specification. The measurements shall be performed at $T_{amb} = +25 \pm 3$ °C.
- 4.8.4 Conditions for Operating Life Tests (Part of Endurance Testing)
The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. The conditions for operating life testing shall be the same as specified in Table 5 for the burn-in test.
- 4.8.5 Electrical Circuits for Operating Life Tests
Not applicable.
- 4.8.6 Conditions for High Temperature Storage Test (Part of Endurance Testing)
The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 5000. The conditions for high temperature storage shall be $T_{amb} = +200(+0 - 5)$ °C.

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**TABLE 6 - ELECTRICAL MEASUREMENTS INTERMEDIATE POINTS AND ON
COMPLETION OF ENDURANCE TESTING**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	
4	Collector-Emitter Cut-off Current	I_{CES}	As per Table 2	As per Table 2	-	1.0	mA
6	D.C. Forward Current Transfer Ratio 1	h_{FE1}	As per Table 2	As per Table 2	10	40	-